

TO-8 Photocells

Ceramic Package

Features

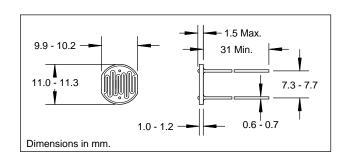
- Three photoconductive materials
- Tolerance: ±40% @1 ftc, ±33% @ 2 ftc

Description

The Silonex TO-8 series of photoconductive cells provide up to eight standard resistance ranges in CdS or CdSe materials. Most of these devices are also available in a hermetic package.

Absolute Maximum Ratings

Operating & Storage Temperature -60° C to $+75^{\circ}$ C Power Dissipation @ 25° C (1) 250 mW



Electrical Characteristics (T_A=25°C, source at 2854 K)

Silonex Part No	Sensitive Material	Spectral Peak (nm)	R @ 1 ftc (Kohms) (3)	R @ 2 ftc (Kohms) (3)	R _{TYP} @ 100 ftc (ohms)		V _{MAX} (Volts) (peak AC or DC)
NSL-4912	Type 4 CdS	515	9.3		150	560	80
NSL-4922			4.0		80	250	80
NSL-4932			1.7		50	100	80
NSL-4942			0.725		30	50	80
NSL-4952			40		860	2400	320
NSL-4962			17		500	1000	320
NSL-4972			7.25		260	400	320
NSL-4982			114		2500	6800	320
NSL-5912				1.5	150	100	170
NSL-5922	Type 5 CdS	550		3.0	300	200	170
NSL-5932				6.0	500	400	250
NSL-5942				9.0	700	600	250
NSL-6922	Type 6	600		0.510	50	300	170
NSL-6952	CdSe	690		2.7	200	720	170

Specifications subject to change without notice.

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Notes: (1) derate linearly to zero at 75°C.

- (2) 5 sec. after removal of test light.
- (3) cells light adapted at 30 to 50 ftc for 16 hrs minimum prior to electrical tests.

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